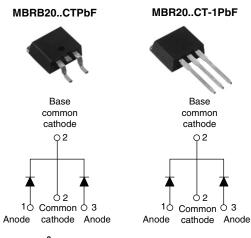


Vishay High Power Products

Schottky Rectifier, 2 x 10 A



D²PAK

TO-262

PRODUCT SUMMARY				
I _{F(AV)}	2 x 10 A			
V _R	35/45 V			
I _{RM}	15 mA at 125 °C			

FEATURES

- 150 °C T_J operation
- Center tap D²PAK and TO-262 packages
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for Q101 level

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform (per device)	20	٨		
I _{FRM}	T _C = 135 °C (per leg)	20	A		
V _{RRM}		35/45	V		
I _{FSM}	$t_p = 5 \ \mu s \ sine$	1060	А		
V _F	10 Apk, T _J = 125 °C	0.57	V		
TJ	Range	- 65 to 150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	MBRB2035CTPbF MBR2035CT-1PbF	MBRB2045CTPbF MBR2045CT-1PbF	UNITS
Maximum DC reverse voltage	V _R	35	45	V
Maximum working peak reverse voltage	V _{RWM}	55		v

* Pb containing terminations are not RoHS compliant, exemptions may apply



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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per leg		T_{C} = 135 °C, rated V_{R}		10	
forward current per device	I _{F(AV)}			20	
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20	Rated V_R , square wave, 20 kHz, $T_C = 135 \degree C$		
		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1060	A
Non-repetitive peak surge current		Surge applied at rated load o single phase, 60 Hz	conditions halfwave,	150	
Non-repetitive avalanche energy per leg	E _{AS}	$T_{J} = 25 \ ^{\circ}C, I_{AS} = 2 \text{ A}, L = 4 \text{ mH}$		8	mJ
Repetitive avalanche current per leg	I _{AR}			А	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS VALUE		VALUES	UNITS
		20 A	T _J = 25 °C	0.84	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	- T _J = 125 °C	0.57	V
		20 A		0.72	
Maximum instantaneous	I _{RM} ⁽¹⁾	T _J = 25 °C T _J = 125 °C	Rated DC voltage	0.1	mA
reverse current	IRM (1)			15	ma
Threshold voltage	V _{F(TO)}	T ₁ = T ₁ maximum		0.354	V
Forward slope resistance	r _t			17.6	mΩ
Maximum junction capacitance	CT	V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 $^{\circ}\text{C}$		600	pF
Typical series inductance	L _S	Measured from top of terminal to mounting plane 8.0		nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER SYMBOL TEST CONDITIONS		TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	TJ		- 65 to 150	°C	
Maximum storage temperature range	T _{Stg}		- 65 to 175		
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	2.0	2.0 0.50 °C/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50		
Approvimate weight			2	g	
Approximate weight			0.07	oz.	
Mounting torque		Non-lubricated threads	6 (5)	kgf · cm	
Mounting torque maximum		Non-lubricated threads	12 (10)	(lbf · in)	
Marking davias		Case style D ² PAK	MBRB20	45CT	
Marking device		Case style TO-262	MBR204	5CT-1	



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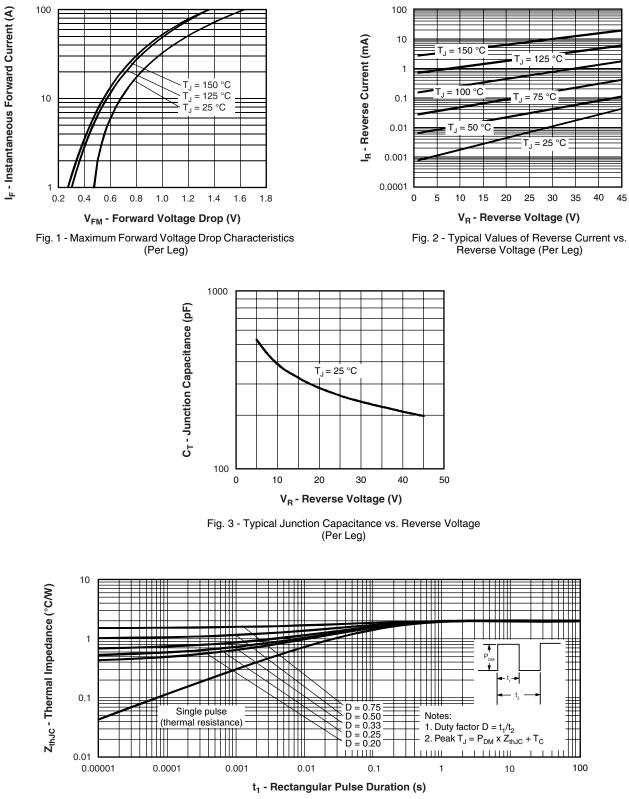
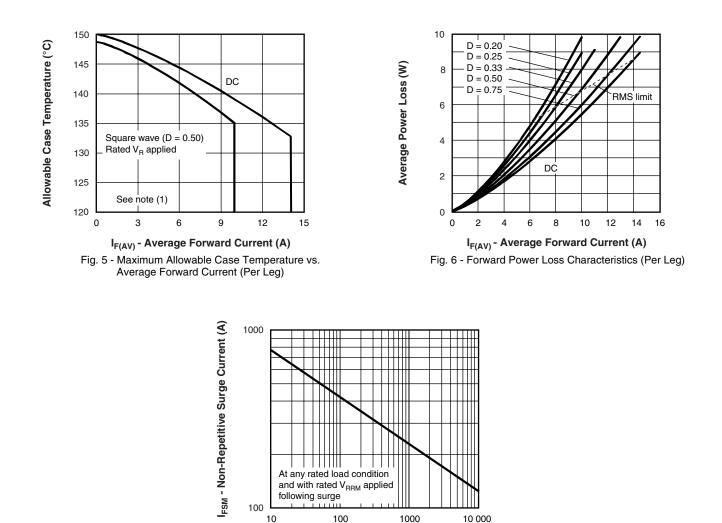


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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tp - Square Wave Pulse Duration (µs) Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

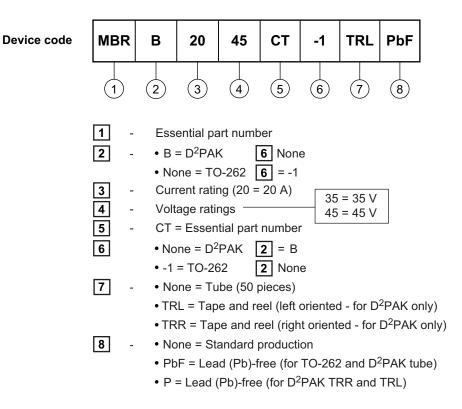
Note

- (1) Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC};$ $Pd = Forward power loss = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)};$ $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 D); I_R \text{ at } V_{R1} = Rated V_R$



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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS			
Dimensions	http://www.vishay.com/doc?95014		
Part marking information	http://www.vishay.com/doc?95008		
Packaging information	http://www.vishay.com/doc?95032		



Vishay

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